

ABSTRACT OF THE DISCLOSURE

A method for producing an electron-emitting device comprising an electroconductive film having an electron-emitting region between electrodes, wherein a
5 step of forming the electron-emitting region in the electroconductive film comprises a step of heating the electroconductive film and a step of energizing the electroconductive film, in an atmosphere in which a gas for promoting cohesion of the electroconductive film
10 exists.